NSN 5961-01-493-2459

Diode Semiconductor Device - Page 1 of 1



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Inclosure Material:
Metal
Overall Length:
Between 0.293 inches and 0.357 inches
Terminal Length:
Between 1.000 inches and 1.625 inches
Overall Diameter:
Between 0.215 inches and 0.235 inches
Function For Which Designed:
Transient suppressor
Mounting Method:
Terminal
Terminal Circle Diameter:
Between 0.025 inches and 0.035 inches
Semiconductor Material:
Silicon
Voltage Rating In Volts Per Characteristic:
28.5 breakdown voltage, dc and 31.5 breakdown voltage, dc
Current Rating Per Characteristic:
5.00 microamperes forward current, average peak
Power Rating Per Characteristic:
1.0 watts small-signal input power, common-collector horsepower metric
Maximum Operating Tempurature Per Measurement Point:
175.0 degrees celsius ambient air
Special Features:
Unipolar type; quality level jantxv
Test Data Document:
81349-mil-prf-19500 specification (includes engineering type bulletins, brochures, etc., that reflect specification type data in specification
format; excludes commercial catalogs, industry directories, and similar trade publications, reflecting general type data on certain
environmental and performance requirements and test conditions that are shown as "typical", "average", "", etc.).
Terminal Type And Quantity:
2 uninsulated wire lead
Specification Data:
81349-mil-prf-19500/500 government specification
Shelf Life:
N/a
Unit Of Measure:

Demilitarization:
No
Fiig:

Mil-prf-19500 spec.

Mil-std (military Standard):

A110a0